

# **連れいた出3040CC**,4**やいた出3060CC**

Data Sheet January 2000 File Number 2772.4

#### 30A, 400V - 600V Ultrafast Dual Diodes

RURH3040CC and RURH3060CC are ultrafast dual diodes ( $t_{rr} < 55$ ns) with soft recovery characteristics. They have a low forward voltage drop and are of planar, silicon nitride passivated, ion-implanted, epitaxial construction.

These devices are intended for use as energy steering/ clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Their low stored charge and ultrafast recovery with soft recovery characteristics minimize ringing and electrical noise in many power switching circuits, thus reducing power loss in the switching transistor.

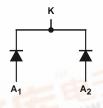
Formerly developmental type TA09903.

## **Ordering Information**

PART NUMBER	PACKAGE	BRAND		
RURH3040CC	TO-218AC	RURH3040C		
RURH3060CC	TO-218AC	RURH3060C		

NOTE: When ordering, use the entire part number.

## Symbol



#### **Features**

	Ultrafast with Soft Recovery<55ns
•	Operating Temperature
•	Reverse Voltage Up to

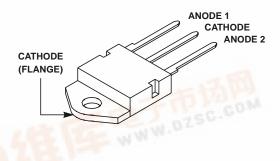
- Avalanche Energy Rated
- · Planar Construction

## **Applications**

- Switching Power Supply
- · Power Switching Circuits
- General Purpose

## **Packaging**

JEDEC TO-218AC



<b>Absolute Maximum Ratings</b> (Per Leg) $T_C = 25^{\circ}C$ , Unless Otherwise Specified			
	RURH3040CC	RURH3060CC	UNITS
Peak Repetitive Reverse VoltageV <sub>RRM</sub>	400	600	V
Working Peak Reverse Voltage	400	600	V
DC Blocking VoltageV <sub>R</sub>	400	600	V
Average Rectified Forward Current	30	30	Α
Repetitive Peak Surge Current I <sub>FRM</sub> (Square Wave 20kHz)	70	70	Α
Nonrepetitive Peak Surge Current I <sub>FSM</sub> (Halfwave 1 Phase 60Hz)	325	325	Α
Maximum Power Dissipation	125	125	W
Avalanche Energy (See Figures 7 and 8)	20	20	mJ
Operating and Storage Temperature	-55 to 175	-55 to 175	οС

#### RURH3040CC, RURH3060CC

**Electrical Specifications** (Per Leg)  $T_C = 25^{\circ}C$ , Unless Otherwise Specified

SYMBOL	TEST CONDITION	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
V <sub>F</sub>	I <sub>F</sub> = 30A	-	-	1.5	-	-	1.5	V
	$I_F = 30A, T_C = 150^{\circ}C$	-	-	1.3	-	-	1.3	V
I <sub>R</sub>	V <sub>R</sub> = 400V	-	-	250	-	-	-	μΑ
	V <sub>R</sub> = 600V	-	-	-	-	-	250	μΑ
	$V_R = 400V, T_C = 150^{\circ}C$	-	-	1	-	-	-	mA
	$V_R = 600V, T_C = 150^{\circ}C$	-	-	-	-	-	1	mA
t <sub>rr</sub>	$I_F = 1A$ , $d_{IF}/dt = 100A/\mu s$	-	-	55	-	-	55	ns
	$I_F = 30A$ , $d_{IF}/dt = 100A/\mu s$	-	-	60	-	-	60	ns
t <sub>a</sub>	$I_F = 30A$ , $d_{IF}/dt = 100A/\mu s$	-	30	-	-	30	-	ns
t <sub>b</sub>	$I_F = 30A$ , $d_{IF}/dt = 100A/\mu s$	-	20	-	-	20	-	ns
$R_{ heta JC}$		-	-	1.2	-	-	1.2	°C/W

#### **DEFINITIONS**

 $V_F$  = Instantaneous forward voltage (pw = 300 $\mu$ s, D = 2%).

 $I_R$  = Instantaneous reverse current.

 $t_{rr}$  = Reverse recovery time at  $dI_F/dt$  = 100A/ $\mu$ s (See Figure 6), summation of  $t_a$  +  $t_b$ .

 $t_a$  = Time to reach peak reverse current at  $dI_F/dt$  = 100A/ $\mu s$  (See Figure 6).

 $t_b$  = Time from peak  $I_{RM}$  to projected zero crossing of  $I_{RM}$  based on a straight line from peak  $I_{RM}$  through 25% of  $I_{RM}$  (See Figure 6).

 $R_{\theta JC}$  = Thermal resistance junction to case.

pw = Pulse width.

D = Duty cycle.

# **Typical Performance Curves**

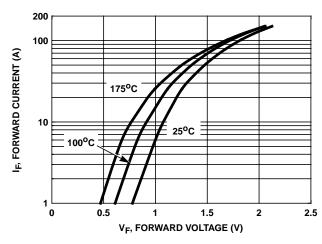


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

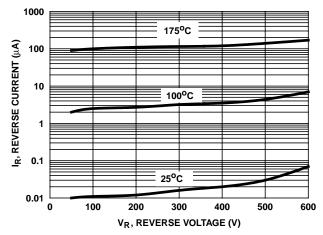


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

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#### RURH3040CC, RURH3060CC

#### Typical Performance Curves (Continued)

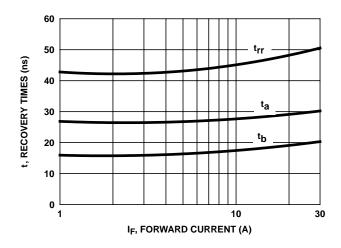


FIGURE 3.  $t_{rr}$ ,  $t_a$  AND  $t_b$  CURVES vs FORWARD CURRENT

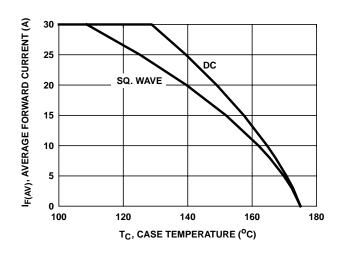


FIGURE 4. CURRENT DERATING CURVE

#### Test Circuits and Waveforms

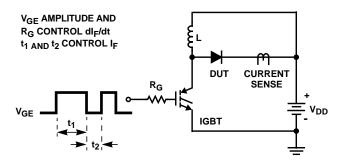


FIGURE 5. t<sub>rr</sub> TEST CIRCUIT

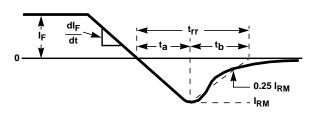


FIGURE 6.  $t_{rr}$  WAVEFORMS AND DEFINITIONS

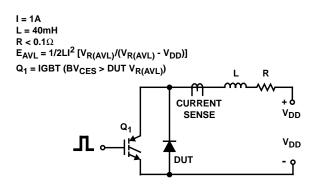


FIGURE 7. AVALANCHE ENERGY TEST CIRCUIT

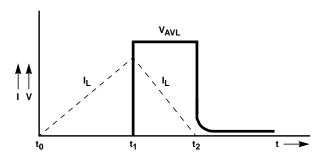


FIGURE 8. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

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